

Amendment to the article

**„Luminescent properties of individual centers „silicon–vacancy“ in CVD nanodiamonds grown on various substrates“
(vol 131. N 2. 2023)**

© D.G. Pasternak, D.A. Kalashnikov, V. Leong, K. Chia, A.M. Romshin, S.V. Kuznetsov,
A.K. Martyanov, V.S. Sedov, L.A. Krivitskii, I.I. Vlasov

An error was made in the affiliation of the authors A.M. Romshin and I.I. Vlasov.

The correct variant:

„Luminescent properties of individual centers “silicon–vacancy“ in CVD nanodiamonds grown on various substrates“

D.G. Pasternak^{1,*}, D.A. Kalashnikov², V. Leong², K. Chia², A.M. Romshin^{1,3}, S.V. Kuznetsov¹, A.K. Martyanov¹,
V.S. Sedov¹, L.A. Krivitsky², I.I. Vlasov^{1,3}

¹ Prokhorov Institute of General Physics, RAS, 119991 Moscow, Russia

² Institute of Materials Science and Engineering, „A*STAR“, 138634 Singapore

³ Moscow Institute of Physics and Technology (State University), 141700 Dolgoprudny, Moscow region, Russia